CROSS-SECTION SAMPLE PREPARATION USING FOCUSED ION BEAM SYSTEM (FIB) FOR TRANSMISSION ELECTRON MICROSCOPY (TEM)

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What is TEM?



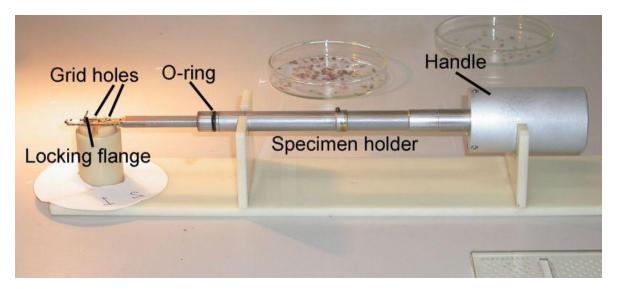
TEM Hitachi HT 7700

What can be observed by TEM:

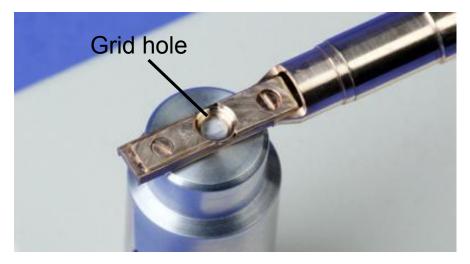
- Thin films and foils;
- meso- micro- and nanoparticles;
- biological specimens;

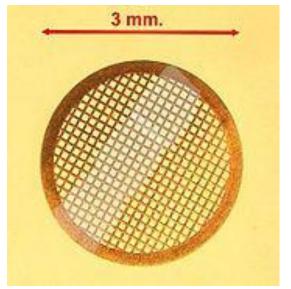
Basic requirements for TEM specimens:

- specimen thickness max 0.1 um;
- Stability under the electron beam and vacuum influence ;



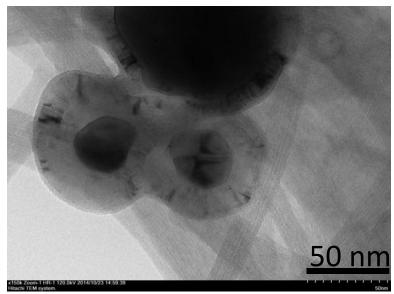
TEM specimen holder



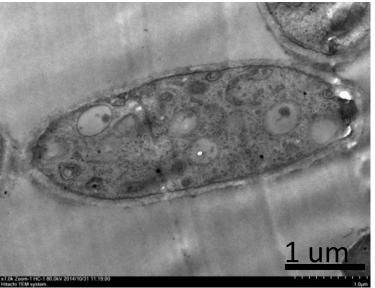


Supporting grid for TEM specimens

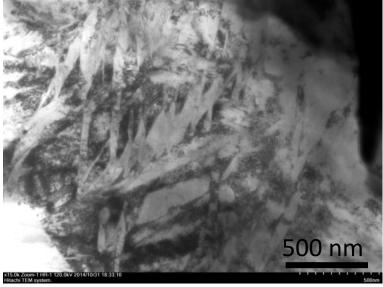
Examples



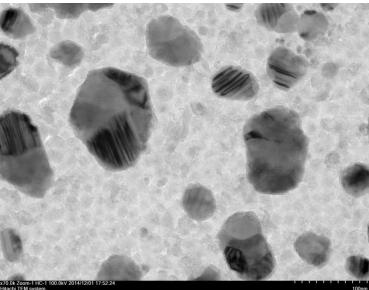
Ni nanoparticles (catalysts) and carbon nanotubes



Neonothopanus nambi (lat.) biological specimen



Ni-Ti thin foil

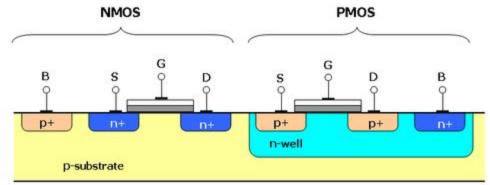


Co-Al2O3 thin film

What is "cross-section"?

cross-section is basic method of observation multi layers

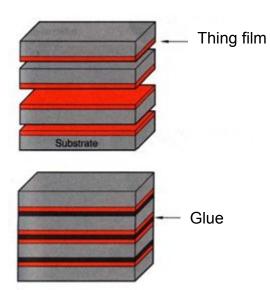
structures



cross-section method allows to observe:

- Interface;
- Thickness of layers;
- Structural defects;
- Interlayer boundaries;

Classic method of cross-section sample preparation



Four pieces of specimens on the silicon substrate are glued together. Billet dimensions: Length 10 mm Width 5 mm Height 5 mm

2

1



cutting 3 mm dia. cylinder for cross-section

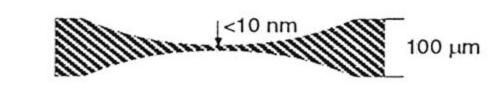


sawing disc of 100 um thickness

4 Thinning the disk up to 10 microns by Dimple Grinder System (Gatan)

<10 um 00 µm





Thinning the disk up to 10 nm by Precision Ion Polishing System (PIPS)



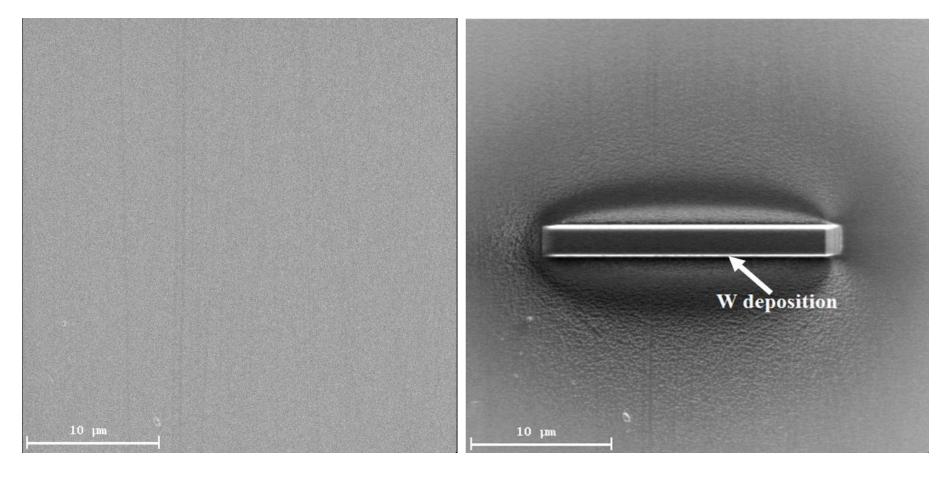
Modern method of cross-section sample preparation



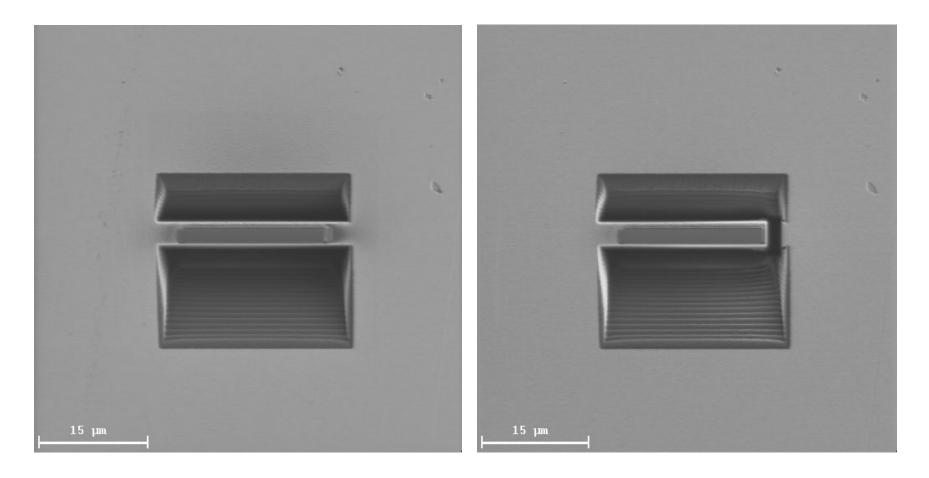
Focused Ion Beam System (FIB) Hitachi FB 2100

Basic steps of cross-section sample preparation by FIB

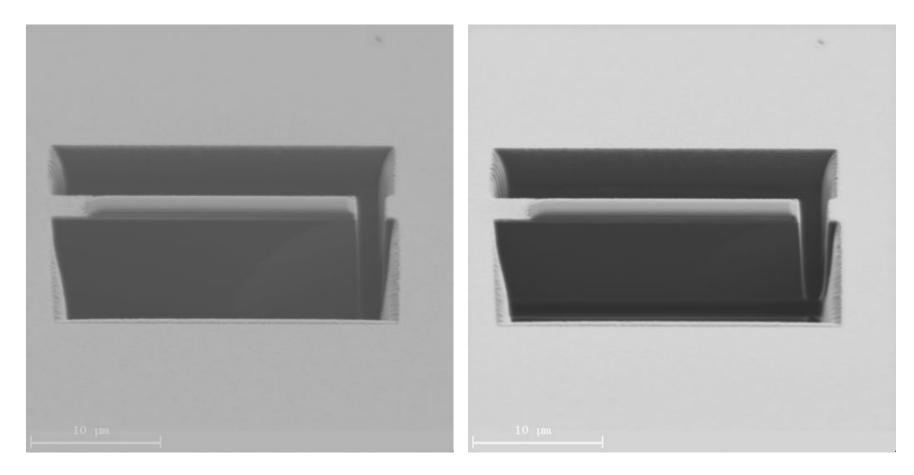
1. Deposition of protective tungsten coating on the sample surface



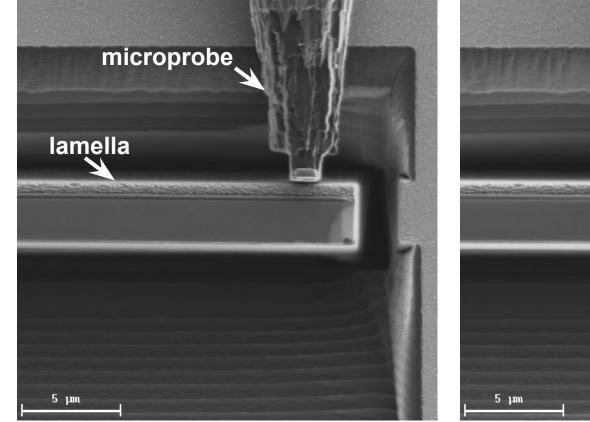
2. Cutting half-finished (lamella)

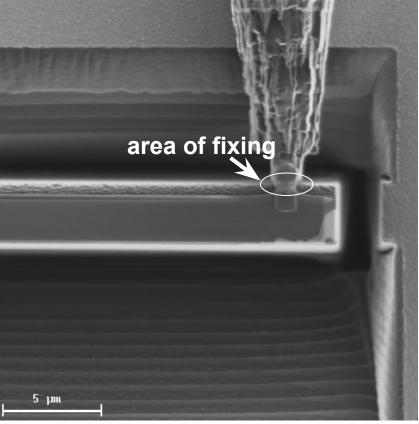


2. Cutting lamella (continuation)

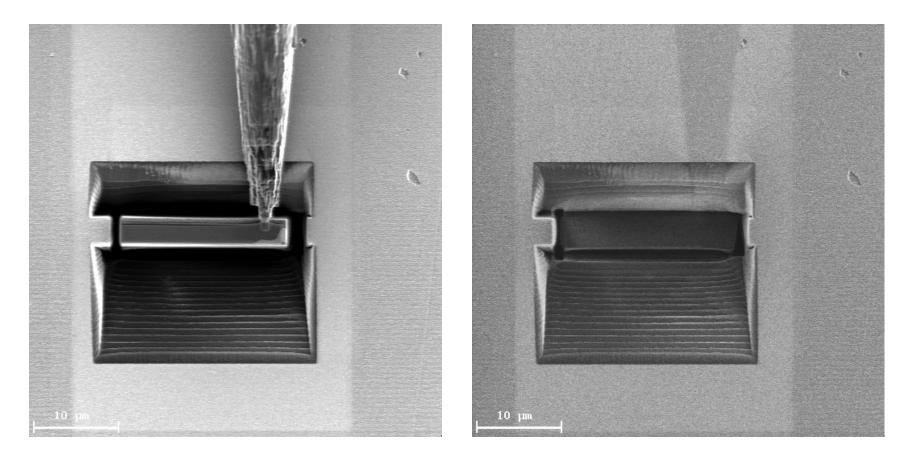


3. Fixing microprobe

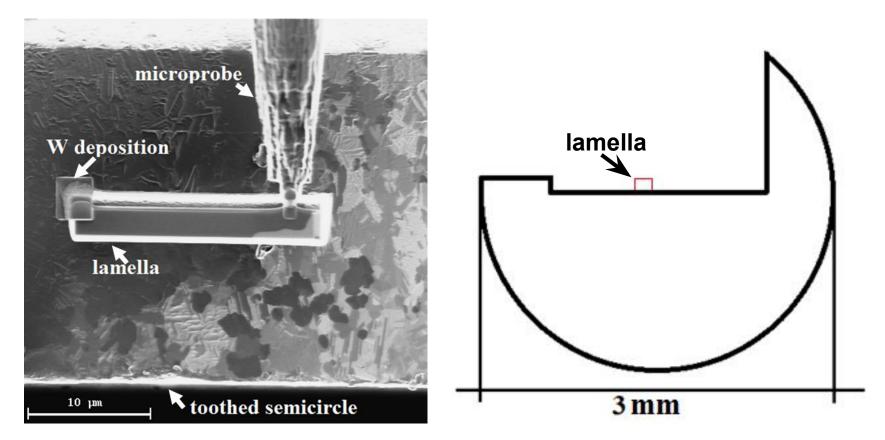




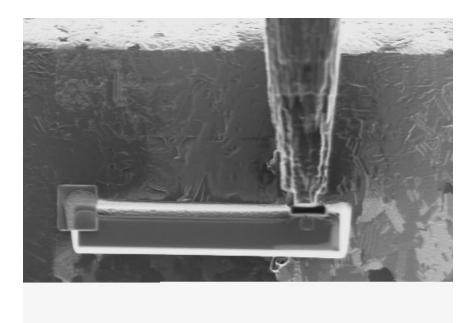
4. Cutting left side and removing lamella

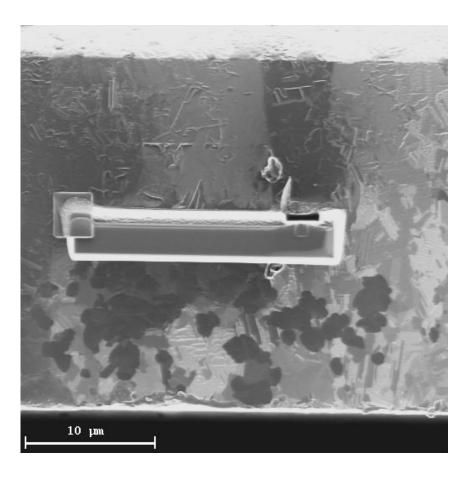


5. Fixing lamella on the toothed semicircle

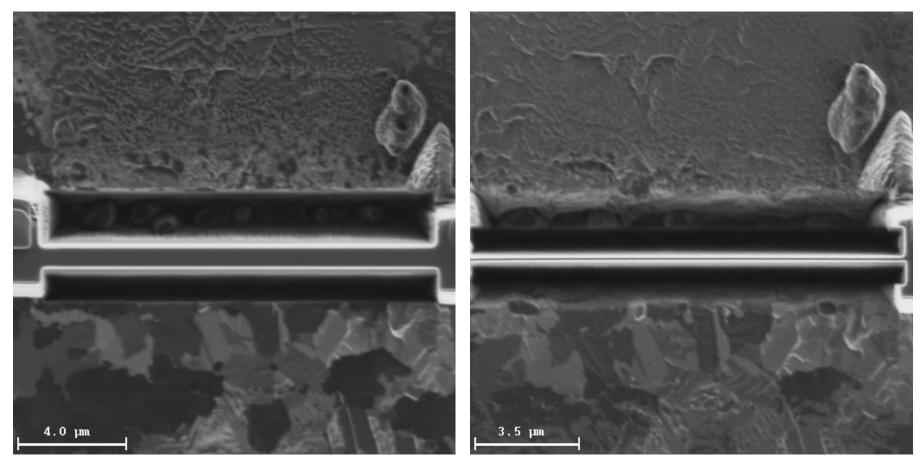


6. Cutting and removing microprobe

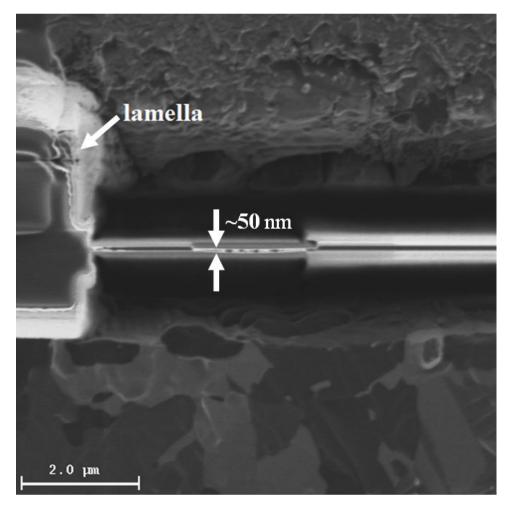




7. Thinning specimen to 50-100 nm

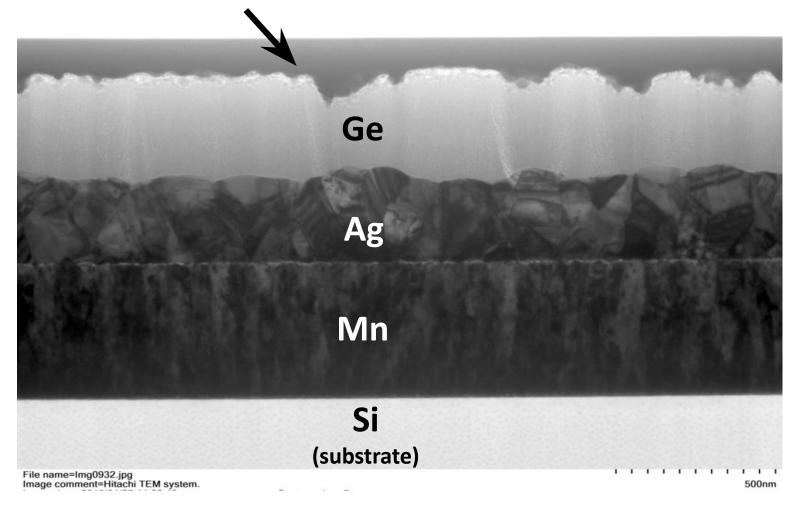


Finish result

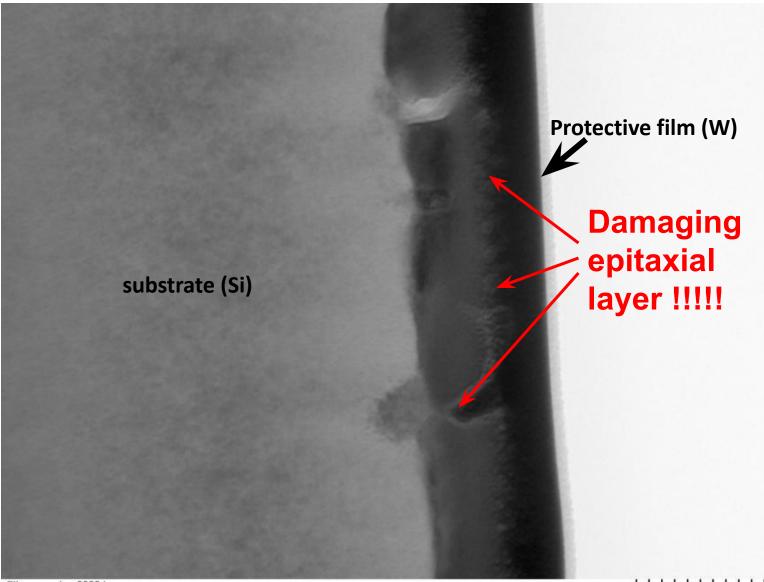


Some features sample preparation with thin layers (thickness less than 300 nm)



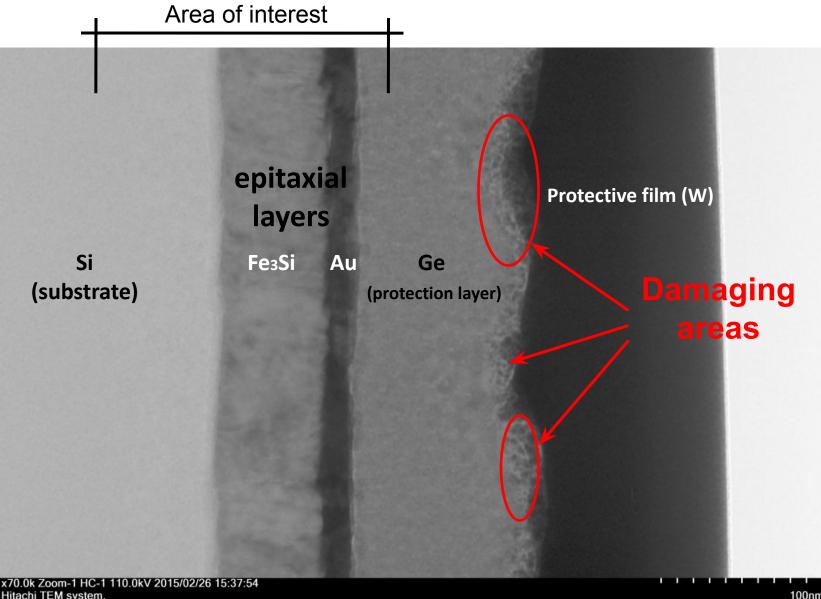






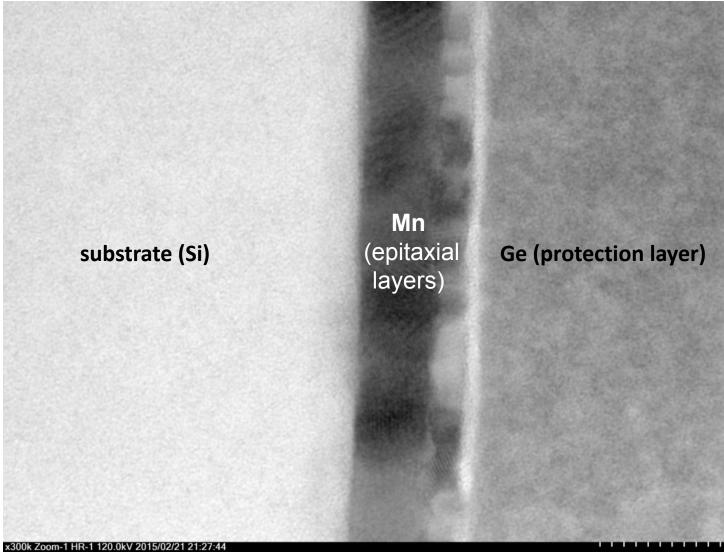
File name=Img0888.jpg Image comment=Hitachi TEM system. 11111111111 100nm

Pre-sputtering of Ge protective layer



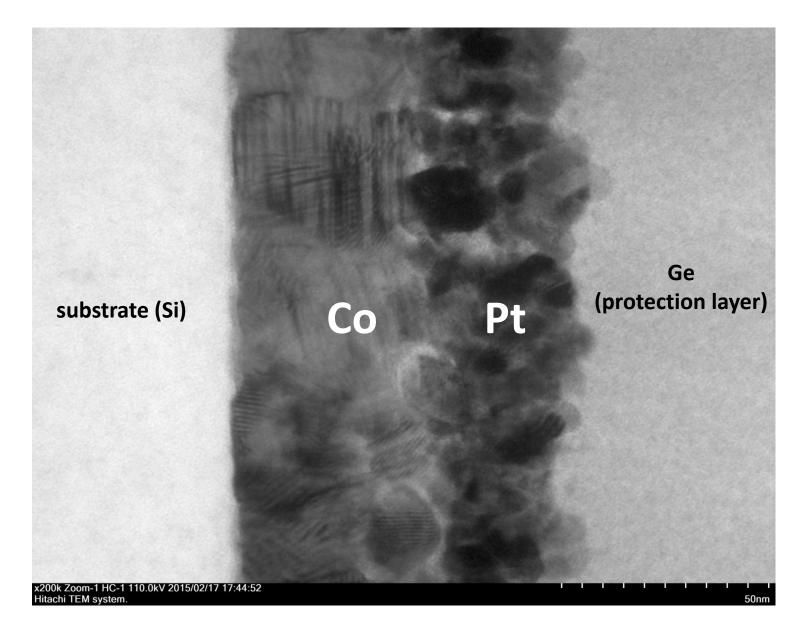
100nm

Examples

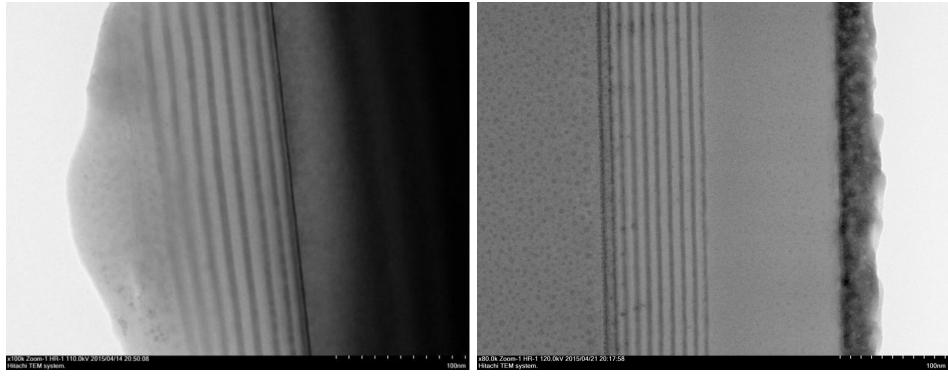


Hitachi TEM system.

20nm



comparison of the two methods



Classic method

FIB method

Thanks for your attention!